### 1. Product profile

### 1.1 General description

PNP general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview** 

| Type number[1] | Package |          | NPN complement |
|----------------|---------|----------|----------------|
|                | NXP     | JEDEC    |                |
| 2PB709ARL      | SOT23   | TO-236AB | 2PD601ARL      |
| 2PB709ASL      |         |          | 2PD601ASL      |
| 2PB709ARL/DG   | SOT23   | TO-236AB | 2PD601ARL/DG   |
| 2PB709ASL/DG   |         |          | 2PD601ASL/DG   |

<sup>[1] /</sup>DG: halogen-free

#### 1.2 Features

- General-purpose transistors
- Two current gain selections
- AEC-Q101 qualified
- Small SMD plastic package

### 1.3 Applications

■ General-purpose switching and amplification

#### 1.4 Quick reference data

Table 2. Quick reference data

| Symbol          | Parameter                 | Conditions  | Min | Тур | Max  | Unit |
|-----------------|---------------------------|---|-----|-----|------|------|
| $V_{CEO}$       | collector-emitter voltage | open base   | -   | -   | -45  | V    |
| I <sub>C</sub>  | collector current         |   | -   | -   | -100 | mA   |
| h <sub>FE</sub> | DC current gain           | $V_{CE} = -10 \text{ V};$ $I_{C} = -2 \text{ mA}$ |     |     |      |      |
|                 | h <sub>FE</sub> group R   |   | 210 | -   | 340  |      |
|                 | h <sub>FE</sub> group S   |   | 290 | -   | 460  |      |



# 2. Pinning information

Table 3. Pinning

| Table 3. | Filling     |                                   |
|----------|-------------|-----------------------------------|
| Pin      | Description | Simplified outline Graphic symbol |
| 1        | base        | <b>—</b> .                        |
| 2        | emitter     | 3                                 |
| 3        | collector   | 1 1 2                             |
|          |             | sym013                            |

# 3. Ordering information

Table 4. Ordering information

| Type number[1] | Package |  |         |
|----------------|---------|--|---------|
|                | Name    | Description                              | Version |
| 2PB709ARL      | -       | plastic surface-mounted package; 3 leads | SOT23   |
| 2PB709ASL      |         |  |         |
| 2PB709ARL/DG   |         |  |         |
| 2PB709ASL/DG   |         |  |         |

[1] /DG: halogen-free

# 4. Marking

Table 5. Marking codes

| Type number  | Marking code <sup>[1]</sup> |
|--------------|-----------------------------|
| 2PB709ARL    | SN*                         |
| 2PB709ASL    | SL*                         |
| 2PB709ARL/DG | SS*                         |
| 2PB709ASL/DG | SZ*                         |

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

### 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

|                  |                           | 5 , (                                   | ,            |            |      |
|------------------|---------------------------|---|--------------|------------|------|
| Symbol           | Parameter                 | Conditions                              | Min          | Max        | Unit |
| $V_{CBO}$        | collector-base voltage    | open emitter                            | -            | <b>-45</b> | V    |
| $V_{CEO}$        | collector-emitter voltage | open base                               | -            | <b>-45</b> | V    |
| $V_{EBO}$        | emitter-base voltage      | open collector                          | -            | -6         | V    |
| I <sub>C</sub>   | collector current         |   | -            | -100       | mA   |
| I <sub>CM</sub>  | peak collector current    | single pulse;<br>$t_p \le 1 \text{ ms}$ | -            | -200       | mA   |
| I <sub>BM</sub>  | peak base current         | single pulse;<br>$t_p \le 1 \text{ ms}$ | -            | -100       | mA   |
| P <sub>tot</sub> | total power dissipation   | $T_{amb} \le 25  ^{\circ}C$             | <u>[1]</u> _ | 250        | mW   |
| Tj               | junction temperature      |   | -            | 150        | °C   |
| T <sub>amb</sub> | ambient temperature       |   | -55          | +150       | °C   |
| T <sub>stg</sub> | storage temperature       |   | -65          | +150       | °C   |
|                  |                           |   |              |            |      |

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### 6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol        | Parameter                                   | Conditions  | Min   | Тур | Max | Unit |
|---------------|---|-------------|-------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] _ | -   | 500 | K/W  |

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

Table 8. Characteristics

 $T_{amb}$  = 25 °C unless otherwise specified.

| Symbol             | Parameter                            | Conditions   | Min   | Тур | Max        | Unit |
|--------------------|--------------------------------------|--|-------|-----|------------|------|
| $I_{CBO}$          | collector-base cut-off               | $V_{CB} = -45 \text{ V}; I_{E} = 0 \text{ A}$                          | -     | -   | -10        | nA   |
| (                  | current                              | $V_{CB} = -45 \text{ V}; I_E = 0 \text{ A};$<br>$T_j = 150 \text{ °C}$ | -     | -   | <b>–</b> 5 | μΑ   |
| I <sub>EBO</sub>   | emitter-base cut-off current         | $V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$                             | -     | -   | -10        | nA   |
| $h_{FE}$           | DC current gain                      | $V_{CE} = -10 \text{ V}; I_C = -2 \text{ mA}$                          |       |     |            |      |
|                    | h <sub>FE</sub> group R              |  | 210   | -   | 340        |      |
|                    | h <sub>FE</sub> group S              |  | 290   | -   | 460        |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage | $I_C = -100 \text{ mA};$<br>$I_B = -10 \text{ mA}$                     | [1] _ | -   | -500       | mV   |

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 Table 8.
 Characteristics ...continued

 $T_{amb}$  = 25 °C unless otherwise specified.

| anno           | •                       |   |     |     |     |      |
|----------------|-------------------------|---|-----|-----|-----|------|
| Symbol         | Parameter               | Conditions  | Min | Тур | Max | Unit |
| $f_T$          | transition frequency    | $V_{CE} = -10 \text{ V}; I_{C} = -1 \text{ mA};$<br>f = 100 MHz |     |     |     |      |
|                | h <sub>FE</sub> group R |   | 70  | -   | -   | MHz  |
|                | h <sub>FE</sub> group S |   | 80  | -   | -   | MHz  |
| C <sub>c</sub> | collector capacitance   | $V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz    | -   | -   | 5   | pF   |

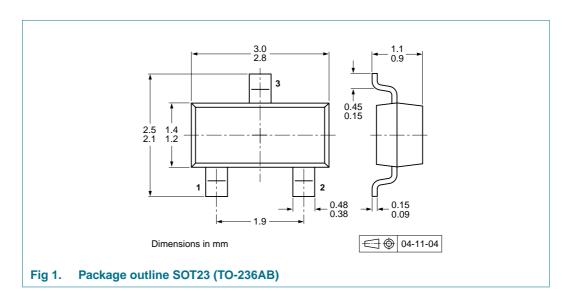
<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



# 10. Packing information

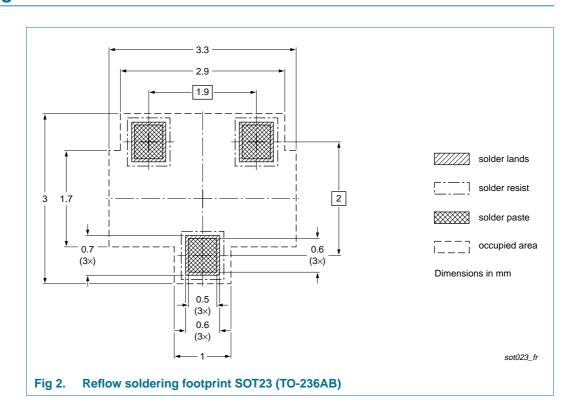
Table 9. Packing methods

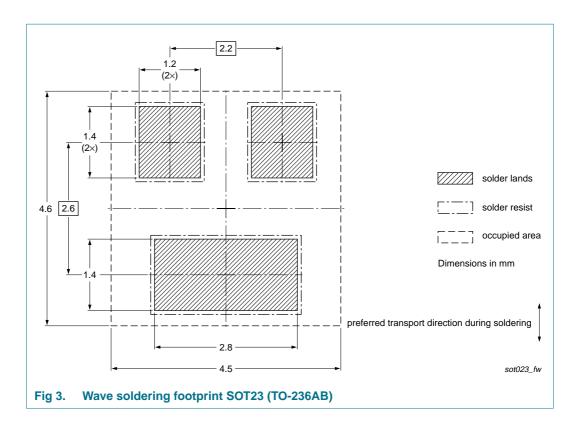
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number[2] | Package | Description                    | Packing | Packing quantity |  |  |
|----------------|---------|--------------------------------|---------|------------------|--|--|
|                |         |                                | 3000    | 10000            |  |  |
| 2PB709ARL      | SOT23   | 4 mm pitch, 8 mm tape and reel | -215    | -235             |  |  |
| 2PB709ASL      |         |                                |         |                  |  |  |
| 2PB709ARL/DG   |         |                                |         |                  |  |  |
| 2PB709ASL/DG   |         |                                |         |                  |  |  |

- [1] For further information and the availability of packing methods, see Section 14.
- [2] /DG: halogen-free

# 11. Soldering





# **2PB709ARL**; **2PB709ASL**

45 V, 100 mA PNP general-purpose transistors

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# 12. Revision history

### Table 10. Revision history

| Document ID | Release date | Data sheet status  | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| 2PB709AXL_1 | 20081112     | Product data sheet | -             | -          |

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# **2PB709ARL; 2PB709ASL**

45 V, 100 mA PNP general-purpose transistors

### 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# **2PB709ARL**; **2PB709ASL**

45 V, 100 mA PNP general-purpose transistors

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